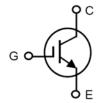
### XPT<sup>™</sup> 650V IGBT GenX3<sup>™</sup>

## IXYA50N65C3 IXYP50N65C3 IXYH50N65C3

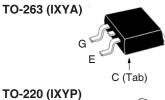
Extreme Light Punch Through IGBT for 20-60kHz Switching

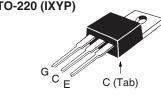


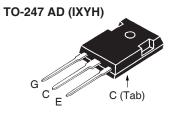
Symbol	Test Conditions	Maximum R	atings
V <sub>CES</sub>	T <sub>,</sub> = 25°C to 175°C	650	V
V <sub>CGR</sub>	$T_J = 25^{\circ}\text{C to } 175^{\circ}\text{C}, R_{GE} = 1\text{M}\Omega$	650	V
V <sub>GES</sub>	Continuous	±20	V
V <sub>GEM</sub>	Transient	±30	V
I <sub>C25</sub>	T <sub>c</sub> = 25°C	132	Α
I <sub>C110</sub>	$T_{c} = 110^{\circ}C$	50	Α
СМ	$T_{\rm C}^{\circ} = 25^{\circ} \text{C}, 1 \text{ms}$	250	A
I <sub>A</sub>	$T_c = 25^{\circ}C$	25	Α
E <sub>AS</sub>	$T_{c} = 25^{\circ}C$	400	mJ
SSOA	$V_{GE} = 15V, T_{VJ} = 150^{\circ}C, R_{G} = 5\Omega$	I <sub>CM</sub> = 100	Α
(RBSOA)	Clamped Inductive Load	$V_{\rm CE} \leq V_{\rm CES}$	
t <sub>sc</sub>	$V_{GE} = 15V, V_{CE} = 360V, T_{J} = 150^{\circ}C$	8	μs
(SCSOA)	$R_{_{G}} = 82\Omega$ , Non Repetitive		
P <sub>c</sub>	T <sub>C</sub> = 25°C	600	W
T <sub>J</sub>		-55 +175	°C
$T_{JM}$		175	°C
T <sub>stg</sub>		-55 +175	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering	300	°C
T <sub>SOLD</sub>	1.6 mm (0.062in.) from Case for 10s	260	°C
F <sub>c</sub>	Mounting Force (TO-263)	1065 / 2.214.6	N/Ib
$M_d$	Mounting Torque (TO-247 & TO-220)	1.13 / 10	Nm/lb.in
Weight	TO-263	2.5	g
	TO-220	3.0	g
	TO-247	6.0	g

Symbol (T <sub>J</sub> = 25°C, U	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic	Values Max.	
BV <sub>CES</sub>	$I_{C} = 250\mu A, V_{GE} = 0V$	650			V
V <sub>GE(th)</sub>	$I_{\rm C}=250\mu{\rm A},\ V_{\rm CE}=V_{\rm GE}$	3.5		6.0	V
I <sub>CES</sub>	$V_{CE} = V_{CES}, V_{GE} = 0V$ $T_{J} = 150^{\circ}C$			15 250	μ <b>Α</b> μ <b>Α</b>
I <sub>GES</sub>	$V_{CE} = 0V, V_{GE} = \pm 20V$			±100	nA
V <sub>CE(sat)</sub>	$I_{c} = 36A, V_{GE} = 15V, \text{ Note 1}$ $T_{J} = 150^{\circ}\text{C}$		1.73 2.10	2.10	V

 $egin{array}{lll} V_{\text{CES}} & = & 650V \\ I_{\text{C110}} & = & 50A \\ V_{\text{CE(sat)}} & \leq & 2.10V \\ t_{\text{fi(typ)}} & = & 26ns \\ \end{array}$ 







G	=	Gate	С	=	Collector
Ε	=	Emitter	Tab	=	Collector

#### **Features**

- Optimized for 20-60kHz Switching
- Square RBSOA
- Avalanche Rated
- Short Circuit Capability
- International Standard Packages

#### **Advantages**

- High Power Density
- Extremely Rugged
- Low Gate Drive Requirement

#### **Applications**

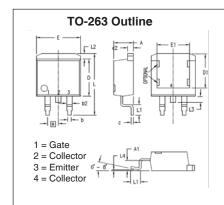
- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts
- High Frequency Power Inverters



Symbol Test Conditions Characteristics Charact			cteristic V	/alues		
$(T_{J} = 25)$	5°C U	nless Otherwise Specified)	Min.	Тур.	Max.	
g <sub>fs</sub>		I <sub>C</sub> = 36A, V <sub>CE</sub> = 10V, Note 1	18	30		S
C <sub>ies</sub>	)			2290		pF
Coes	}	$V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$		135		рF
C <sub>res</sub>	J			50		рF
Q <sub>g(on)</sub>	)			86		nC
$\mathbf{Q}_{qe}$	}	$I_{\rm C} = 36$ A, $V_{\rm GE} = 15$ V, $V_{\rm CE} = 0.5 \bullet V_{\rm CES}$		14		nC
Q <sub>gc</sub>	J			40		nC
t <sub>d(on)</sub>	١			20		ns
t <sub>ri</sub>		Inductive load, T <sub>.i</sub> = 25°C		36		ns
E <sub>on</sub>		$I_{\rm C} = 36A, V_{\rm GE} = 15V$		0.80		mJ
$\mathbf{t}_{d(off)}$	1	$V_{CE} = 400V, R_{G} = 5\Omega$		90		ns
t <sub>fi</sub>		Note 2		26		ns
E <sub>off</sub>				0.47	0.80	mJ
$\mathbf{t}_{d(on)}$	١			19		ns
t <sub>ri</sub>		Inductive load, T <sub>J</sub> = 150°C		37		ns
E <sub>on</sub>	- (	$I_{\rm C} = 36A, V_{\rm GE} = 15V$		1.60		mJ
$\mathbf{t}_{d(off)}$	7	$V_{CE} = 400V, R_{G} = 5\Omega$		113		ns
t <sub>fi</sub>		Note 2		32		ns
E <sub>off</sub>				0.70		mJ
R <sub>thJC</sub>					0.25 °	C/W
$R_{thCS}$		TO-220		0.50		C/W
R <sub>thCS</sub>		TO-247		0.21	0	C/W

#### Notes:

- 1. Pulse test,  $t \le 300\mu s$ , duty cycle,  $d \le 2\%$ .
- 2. Switching times & energy losses may increase for higher V<sub>CF</sub>(clamp), T<sub>J</sub> or R<sub>G</sub>.



CVM	INCHES		MILLIMETERS		
SYM	MIN	MAX	MIN	MAX	
Α	.160	.190	4.06	4.83	
A1	.080.	.110	2.03	2.79	
Ь	.020	.039	0.51	0.99	
b2	.045	.055	1.14	1.40	
С	.016	.029	0.40	0.74	
c2	.045	.055	1.14	1.40	
D	.340	.380	8.64	9.65	
D1	.315	.350	8.00	8.89	
E	.380	.410	9,65	10.41	
E1	.245	.320	6.22	8.13	
е	.100	.100 BSC		BSC	
L	.575	.625	14.61	15.88	
L1	.090	.110	2.29	2.79	
L2	.040	.055	1.02	1.40	
L3	.050	.070	1.27	1.78	
L4	0	.005	0	0.13	

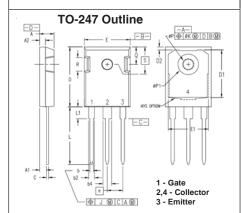
#### PRELIMANARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

# TO-220 Outline

Pins: 1 - Gate 2 - Collector 3 - Emitter

MYZ	INCHES		MILLIMETERS		
2114	MIN	MAX	MIN	MAX	
Α	.170	.190	4.32	4.83	
b	.025	.040	0.64	1.02	
b1	.045	.065	1.15	1.65	
С	.014	.022	0.35	0.56	
D	.580	.630	14.73	16.00	
E	.390	.420	9.91	10.66	
е	.100	.100 BSC 2.54 BSC		BSC	
F	.045	.055	1.14	1.40	
H1	.230	.270	5.85	6.85	
J1	.090	.110	2.29	2.79	
k	0	.015	0	0.38	
L	.500	.550	12.70	13.97	
L1	.110	.230	2.79	5.84	
ØΡ	.139	.161	3.53	4.08	
Q	.100	.125	2.54	3.18	



Dim	Millimeter		Inches	
Dim.	min	max	min	max
A	4.70	5.30	0.185	0.209
A1	2.21	2.59	0.087	0.102
A2	1.50	2.49	0.059	0.098
b	0.99	1.40	0.039	0.055
b2	1.65	2.39	0.065	0.094
b4	2.59	3.43	0.102	0.135
С	0.38	0.89	0.015	0.035
D	20.79	21.45	0.819	0.845
D1	13.07		0.515	
D2	0.51	1.35	0.020	0.053
E	15.48	16.24	0.610	0.640
E1	13.45	(*)	0.53	-
E2	4.31	5.48	0.170	0.216
е	5.45	BSC	0.215	BSC
L	19.80	20.30	0.078	0.800
L1		4.49		0.177
ØР	3.55	3.65	0.140	0.144
ØP1	- 1	7.39	-	0.290
Q	5.38	6.19	0.212	0.244
S	6.14 BSC		0.242	BSC

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.





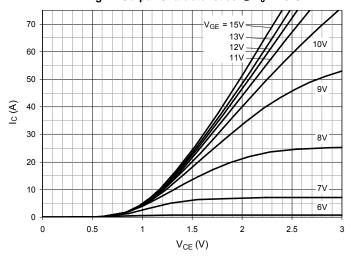


Fig. 2. Extended Output Characteristics @ T<sub>J</sub> = 25°C

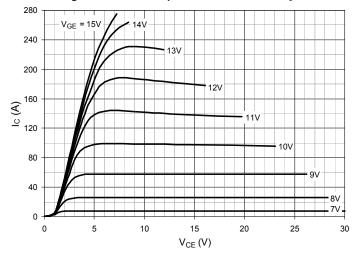


Fig. 3. Output Characteristics @ T<sub>J</sub> = 150°C

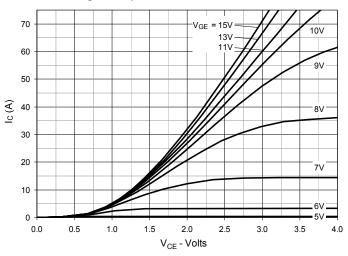


Fig. 4. Dependence of V<sub>CE(sat)</sub> on Junction Temperature

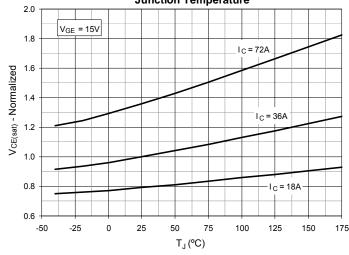


Fig. 5. Collector-to-Emitter Voltage vs.

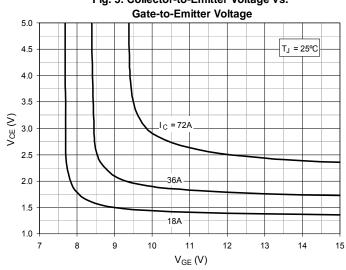
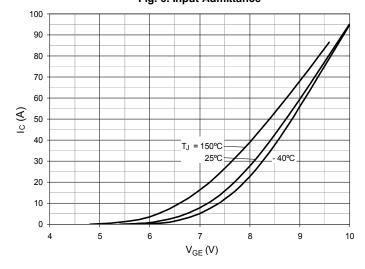
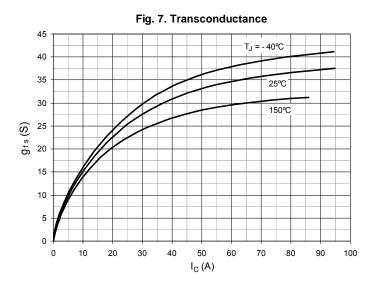
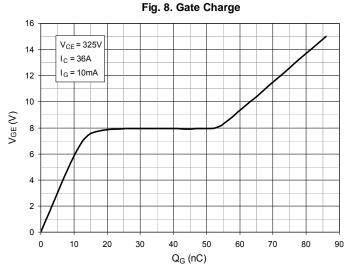


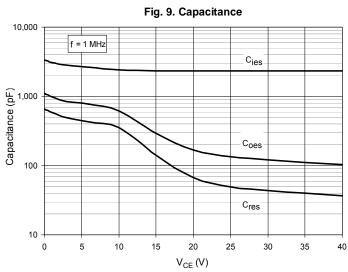
Fig. 6. Input Admittance

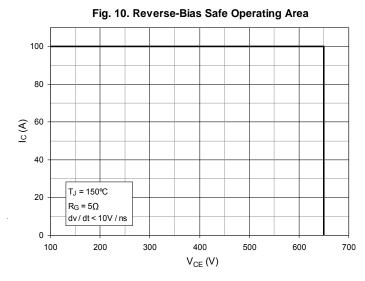


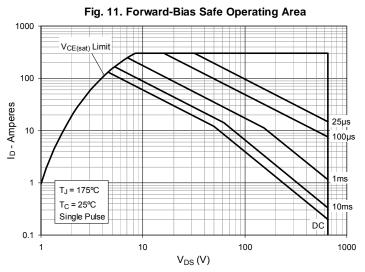


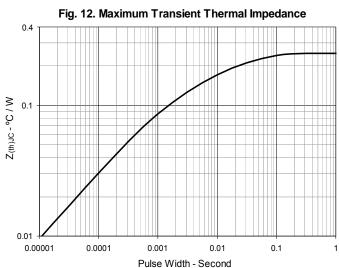












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Fig. 13. Inductive Switching Energy Loss vs.

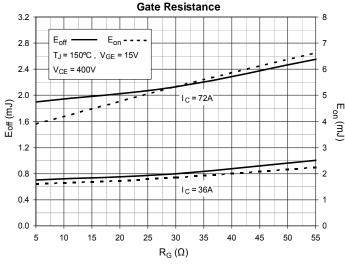


Fig. 15. Inductive Switching Energy Loss vs.

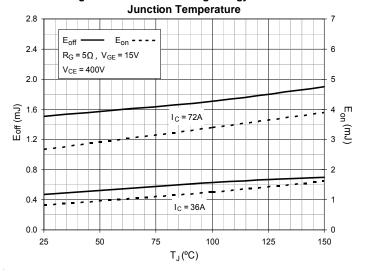


Fig. 17. Inductive Turn-off Switching Times vs.

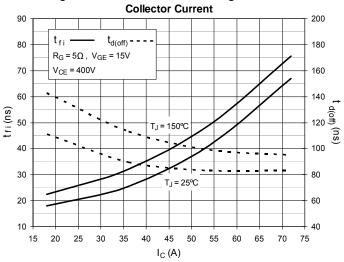


Fig. 14. Inductive Switching Energy Loss vs.

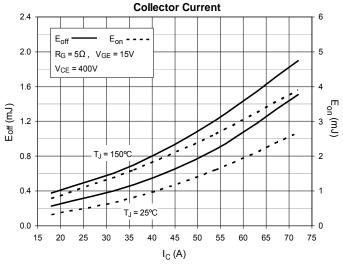


Fig. 16. Inductive Turn-off Switching Times vs.

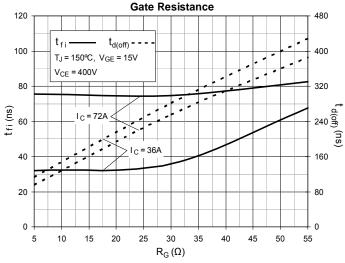
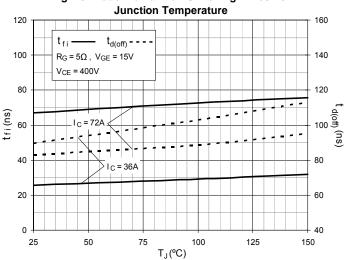


Fig. 18. Inductive Turn-off Switching Times vs.





# IXYA50N65C3 IXYP50N65C3 IXYH50N65C3

Fig. 19. Inductive Turn-on Switching Times vs.

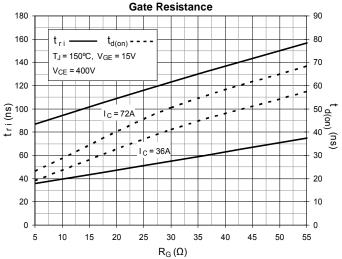


Fig. 20. Inductive Turn-on Switching Times vs.

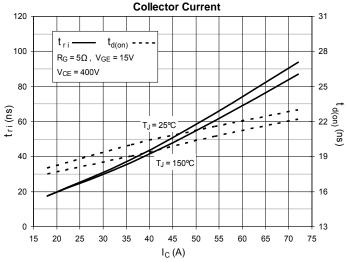


Fig. 21. Inductive Turn-on Switching Times vs. Junction Temperature

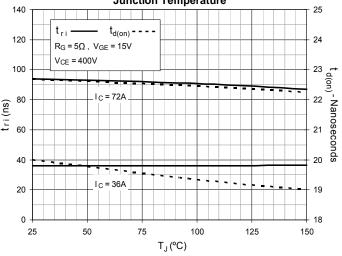


Fig. 22. Maximum Peak Load Current vs. Frequency

